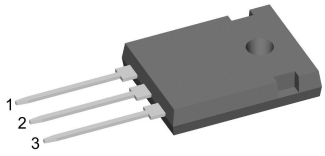
Schottky Diode

V_{RRM}	=	45 V
I_{FAV}	= 2x	30 A
V_F	=	0.58 V

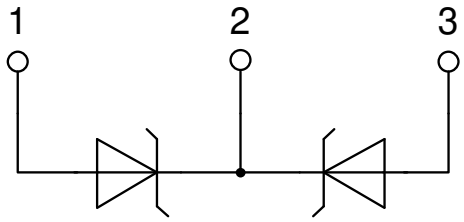
High Performance Schottky Diode
Low Loss and Soft Recovery
Common Cathode

Part number

DSSK60-0045A



Backside: cathode



Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

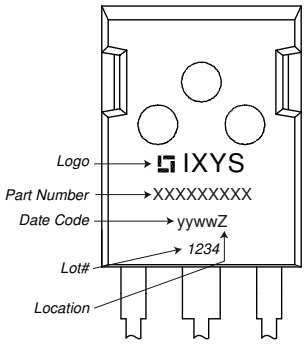
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Schottky				Ratings			
Symbol	**Definition**	**Conditions**		**min.**	**typ.**	**max.**	**Unit**
V_{RSM}	*max. non-repetitive reverse blocking voltage*		T_{VJ} = 25°C			45	V
V_{RRM}	*max. repetitive reverse blocking voltage*		T_{VJ} = 25°C			45	V
I_R	*reverse current, drain current*	V_R = 45 V	T_{VJ} = 25°C			1	mA
		V_R = 45 V	T_{VJ} = 125°C			10	mA
V_F	*forward voltage drop*	I_F = 30 A	T_{VJ} = 25°C			0.70	V
		I_F = 60 A				0.83	V
		I_F = 30 A	T_{VJ} = 125°C			0.58	V
		I_F = 60 A				0.73	V
I_{FAV}	*average forward current*	T_C = 150°C	T_{VJ} = 175°C			30	A
		rectangular d = 0.5					
V_{F0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 175°C			0.37	V
r_F	*slope resistance* }					4.9	mΩ
R_{thJC}	*thermal resistance junction to case*					1.1	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.25		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			135	W
I_{FSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine; V_R = 0 V	T_{VJ} = 45°C			500	A
C_J	*junction capacitance*	V_R = 5 V f = 1 MHz	T_{VJ} = 25°C		1.94		nF
E_{AS}	*non-repetitive avalanche energy*	I_{AS} = 18 A L = 180 µH	T_{VJ} = 25°C			46	mJ
I_{AR}	*repetitive avalanche current*	V_A = 1.5·V_R typ. f = 10 kHz				1.8	A

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Package TO-247			Ratings			
Symbol	**Definition**	**Conditions**	**min.**	**typ.**	**max.**	**Unit**
I_{RMS}	*RMS current*	per terminal 1)			70	A
T_{VJ}	*virtual junction temperature*		-55		175	°C
T_{op}	*operation temperature*		-55		150	°C
T_{stg}	*storage temperature*		-55		150	°C
Weight				6		g
M_D	*mounting torque*		0.8		1.2	Nm
F_C	*mounting force with clip*		20		120	N

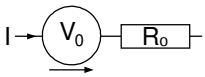
Product Marking



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSSK60-0045A	DSSK60-0045A	Tube	30	502510

Equivalent Circuits for Simulation

** on die level* $T_{VJ} = 175°C$

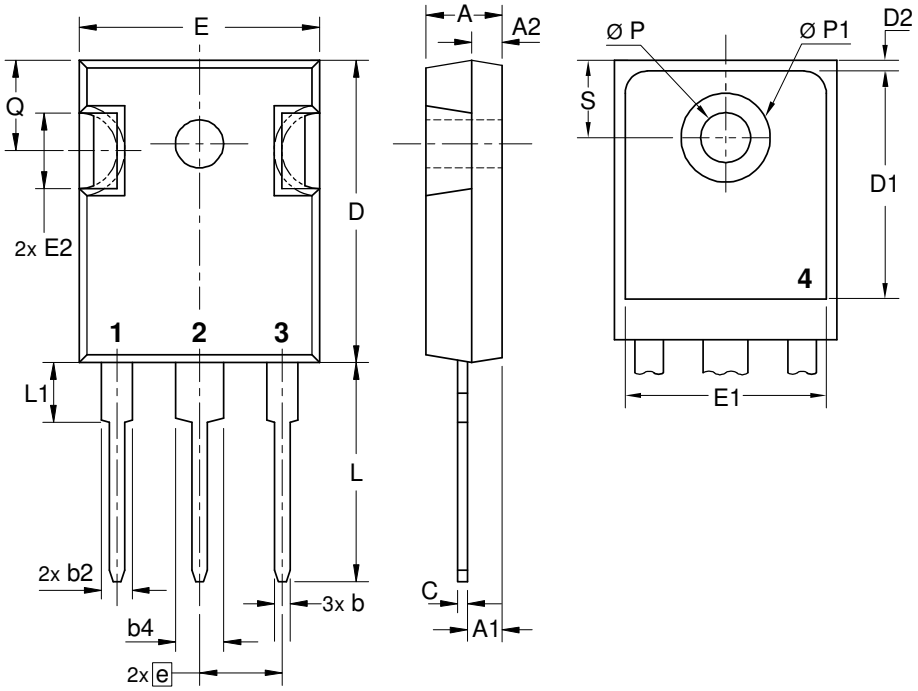


Schottky

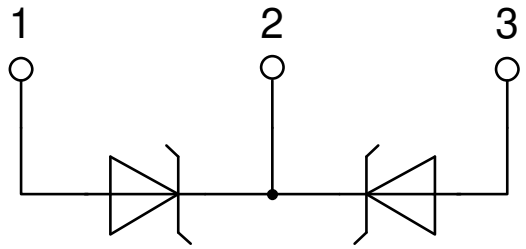
$V_{0\,max}$	*threshold voltage*	0.37	V
$R_{0\,max}$	*slope resistance **	2.4	mΩ

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Outlines TO-247



Sym.	Inches		Millimeter	
	min.	max.	min.	max.
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.215 BSC		5.46 BSC	
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39



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Schottky

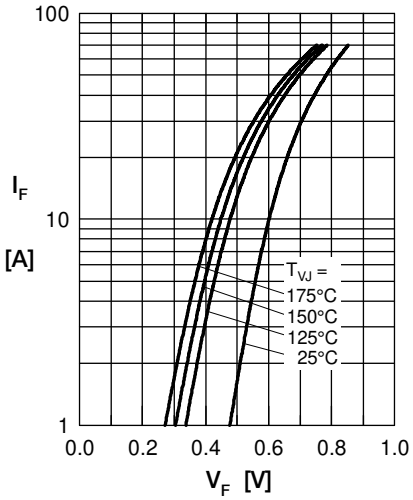


Fig. 1 Max. forward voltage drop characteristics

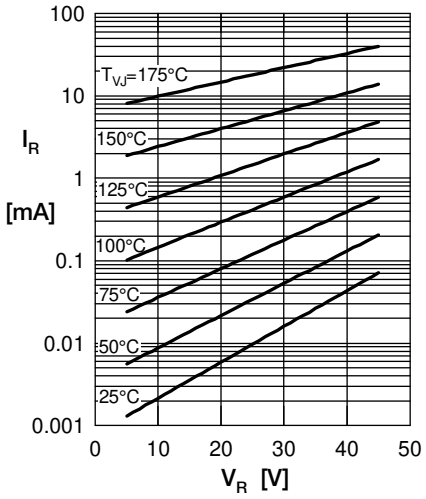


Fig. 2 Typ. reverse current I_R vs. reverse voltage V_R

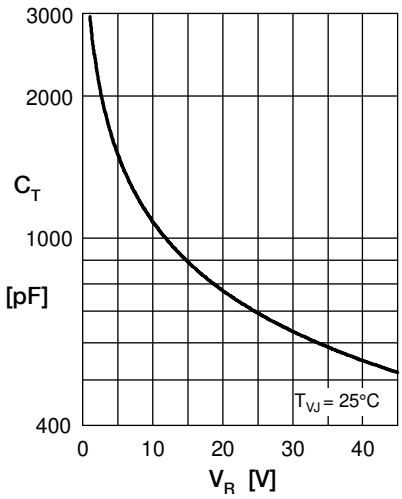


Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_R

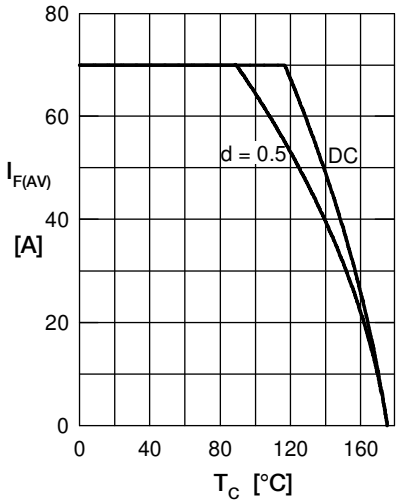


Fig. 4 Average forward current $I_{F(AV)}$ vs. case temp. T_C

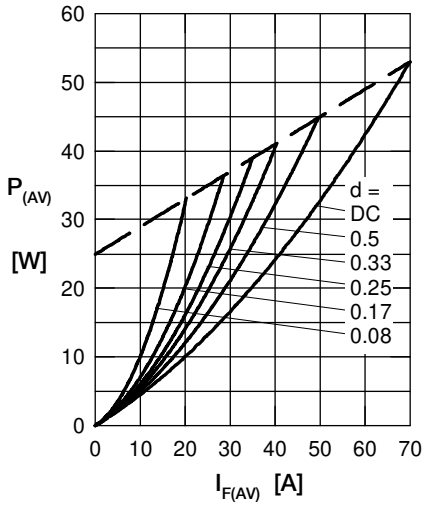


Fig. 5 Forward power loss characteristics

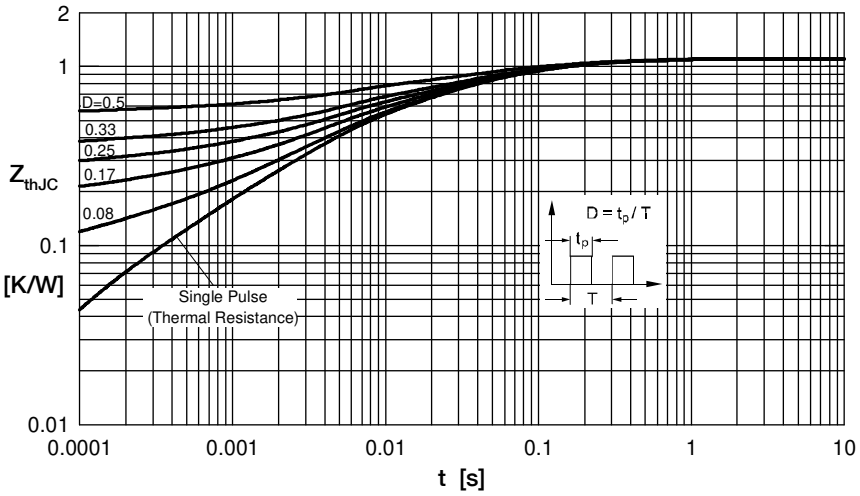


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode

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